

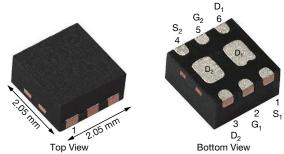
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Vishay Siliconix

Dual N-Channel 20 V (D-S) MOSFET

PRODUCT SUMMARY									
V _{DS} (V)	R _{DS(on)} (Ω) MAX.	I _D (A)	Q _g (TYP.)						
20	0.034 at V _{GS} = 4.5 V	4.5 ^a							
	0.037 at V _{GS} = 3.7 V	4.5 ^a	5.4 nC						
	0.045 at V _{GS} = 2.5 V	4.5 ^a							

PowerPAK® SC-70-6L Dual



Marking Code: CK
Ordering Information:

SiA936EDJ-T1-GE3 (Lead (Pb)-free and Halogen-free)

FEATURES

- TrenchFET® Power MOSFET
- Thermally enhanced PowerPAK® SC-70 package
 - Small footprint area
 - Low on-resistance
- Typical ESD protection: 2000 V (HBM)
- 100 % R_g tested

 Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

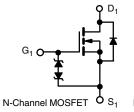


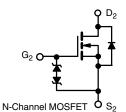
RoHS COMPLIANT

HALOGEN FREE

APPLICATIONS

- Portable devices such as smart phones, tablet PCs and mobile computing
 - Load switch
 - DC/DC converter
 - Power management





ABSOLUTE MAXIMUM RATING	S (T _A = 25 °C, t	ınless otherwis	se noted)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V _{DS}	20	V	
Gate-Source Voltage		V _{GS}	± 12	V	
	T _C = 25 °C		4.5 ^a		
Continuous Drain Coursent /T 150 °C	T _C = 70 °C	1 . 🗆	4.5 ^a		
Continuous Drain Current (T _J = 150 °C)	T _A = 25 °C	I _D	4.5 ^{a,b,c}		
	T _A = 70 °C	1	4.5 ^{a,b,c}	Α	
Pulsed Drain Current (t = 100 μs)	•	I _{DM}	20		
Continuous Courses Drain Diade Current	T _C = 25 °C		4.5 ^a		
Continuous Source-Drain Diode Current	T _A = 25 °C	l _s –	1.6 ^{b,c}		
	T _C = 25 °C		7.8		
Maniero Daniero Dispiration	T _C = 70 °C	1 5 -	5	w	
Maximum Power Dissipation	T _A = 25 °C	P _D	1.9 ^{b,c}	VV	
	T _A = 70 °C	1	1.2 b,c		
Operating Junction and Storage Temperature	T _J , T _{stg}	-55 to 150	°C		
Soldering Recommendations (Peak Temperature	ature) ^{d,e}		260		

THERMAL RESISTANCE RATINGS									
PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT				
Maximum Junction-to-Ambient ^{b,f} t ≤ 5		R _{thJA}	52	65	°C/W				
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	12.5	16]				

Notes

- a. Package limited.
- b. Surface mounted on 1" x 1" FR4 board.
- c. t = 5 s
- d. See solder profile (<u>www.vishay.com/doc?73257</u>). The PowerPAK SC-70 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.
- f. Maximum under steady state condition is 110 °C/W.

Document Number: 62929

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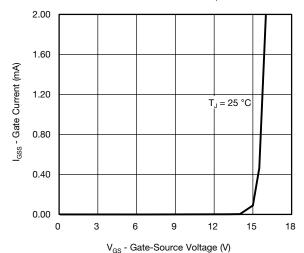
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	20			V	
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$	L 050A		24		>//00	
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	- I _D = 250 μA		-3.2		mV/°C	
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	0.6		1.3	V	
Cata Cauraa Laakaga		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$			± 0.2	μΑ	
Gate-Source Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 12 V			± 10		
Zoro Coto Voltago Drain Current		V _{DS} = 20 V, V _{GS} = 0 V			1		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 20 V, V _{GS} = 0 V, T _J = 55 °C			10		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	10			Α	
		V _{GS} = 4.5 V, I _D = 4 A		0.027	0.034		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 3.7 V, I _D = 3 A		0.029	0.037	Ω	
		V _{GS} = 2.5 V, I _D = 3 A		0.035	0.045		
Forward Transconductance a	9 _{fs}	V _{DS} = 10 V, I _D = 4 A		22		S	
Dynamic ^b							
Total Cata Charge	Qg	V _{DS} = 10 V, V _{GS} = 10 V, I _D = 6 A		11.3	17	nC	
Total Gate Charge				5.4	8.1		
Gate-Source Charge	Q_{gs}	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 6 \text{ A}$		1			
Gate-Drain Charge	Q_{gd}			1.3			
Gate Resistance	R_g	f = 1 MHz	0.4	1.8	3.6	Ω	
Turn-On Delay Time	t _{d(on)}			10	20		
Rise Time	t _r	$V_{DD} = 10 \text{ V}, R_{L} = 2 \Omega$		32	65		
Turn-Off DelayTime	t _{d(off)}	$I_D \cong 5 \text{ A}, V_{GEN} = 4.5 \text{ V}, R_g = 1 \Omega$		22	45		
Fall Time	t _f			10	20		
Turn-On Delay Time	t _{d(on)}			10	20	ns	
Rise Time	t _r	$V_{DD} = 10 \text{ V, R}_{L} = 2 \Omega$		10	20	-	
Turn-Off DelayTime	t _{d(off)}	$I_D \cong 5 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 1 \Omega$		20	40		
Fall Time	t _f			10	20		
Drain-Source Body Diode Characteristic	s						
Continuous Source-Drain Diode Current	I _S	T _C = 25 °C			4.5		
Pulse Diode Forward Current	se Diode Forward Current I _{SM}				20	A	
Body Diode Voltage	V _{SD}	I _S = 5 A, V _{GS} = 0 V		0.84	1.2	V	
Body Diode Reverse Recovery Time	t _{rr}			10	20	ns	
Body Diode Reverse Recovery Charge	Q _{rr}	L 5 A dl/d+ 100 A/::5 T 05 °C		4	10	nC	
Reverse Recovery Fall Time	t _a	$I_F = 5 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, T_J = 25 ^{\circ}\text{C}$		6		ns	
Reverse Recovery Rise Time	t _b	1		4			

Notes

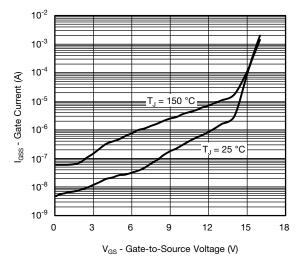
- a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

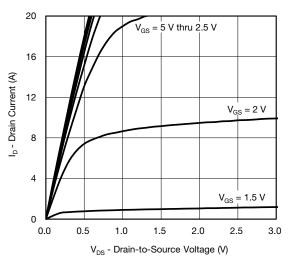




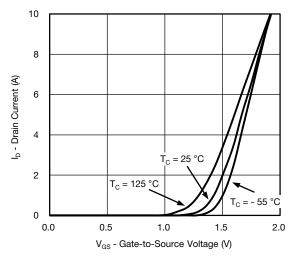
Gate Current vs. Gate-Source Voltage



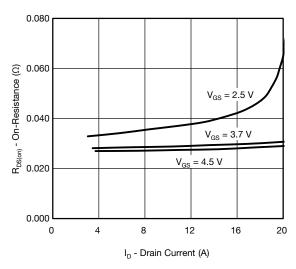
Gate Current vs. Gate-Source Voltage



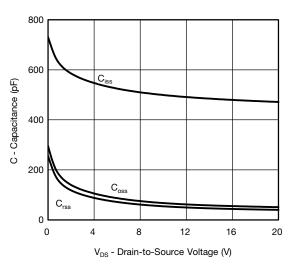
Output Characteristics



Transfer Characteristics

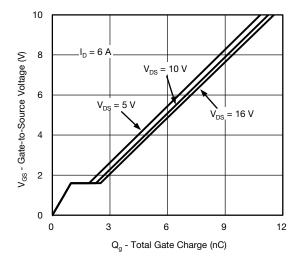


On-Resistance vs. Drain Current and Gate Voltage

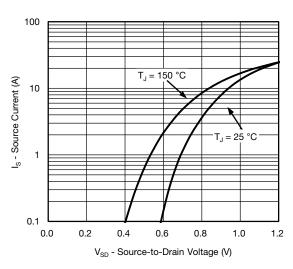


Capacitance

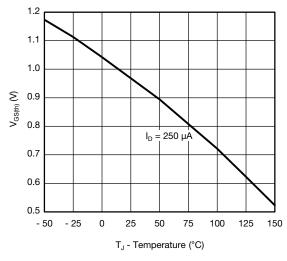




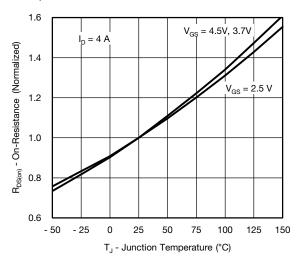
Gate Charge



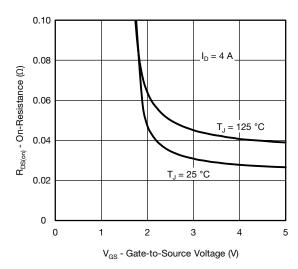
Source-Drain Diode Forward Voltage



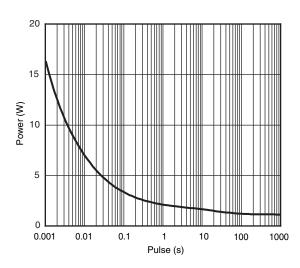
Threshold Voltage



On-Resistance vs. Junction Temperature

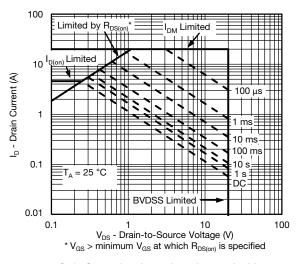


On-Resistance vs. Gate-to-Source Voltage



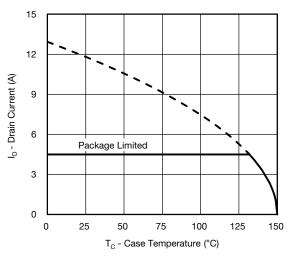
Single Pulse Power (Junction-to-Ambient)

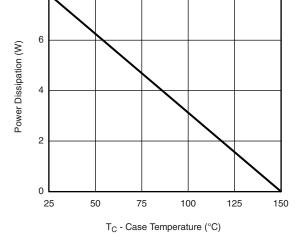




Safe Operating Area, Junction-to-Ambient

8



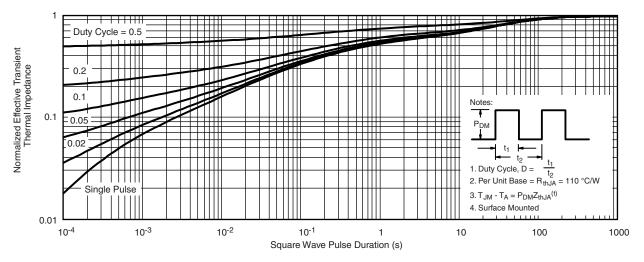


Current Derating*

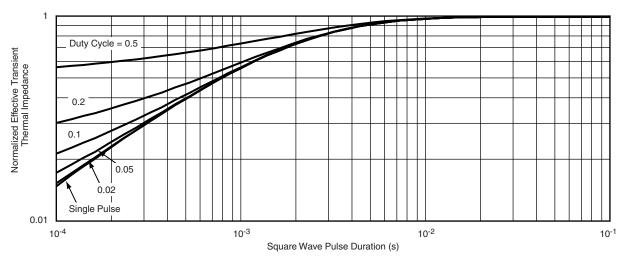
Power Derating

^{*} The power dissipation P_D is based on $T_{J(max.)}$ = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.





Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

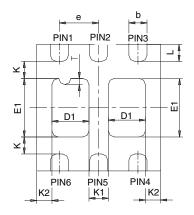
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg262929.



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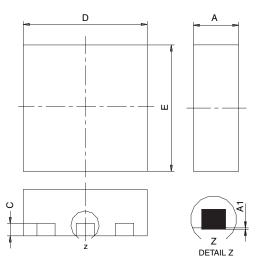
PowerPAK® SC70-6L





BACKSIDE VIEW OF SINGLE

BACKSIDE VIEW OF DUAL



- All dimensions are in millimeters
 Package outline exclusive of mold flash and metal burr
 Package outline inclusive of plating

		SINGLE PAD						DUAL PAD					
DIM	M	ILLIMETER	RS	INCHES			MILLIMETERS			INCHES			
	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	
Α	0.675	0.75	0.80	0.027	0.030	0.032	0.675	0.75	0.80	0.027	0.030	0.032	
A 1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002	
b	0.23	0.30	0.38	0.009	0.012	0.015	0.23	0.30	0.38	0.009	0.012	0.015	
С	0.15	0.20	0.25	0.006	0.008	0.010	0.15	0.20	0.25	0.006	0.008	0.010	
D	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085	
D1	0.85	0.95	1.05	0.033	0.037	0.041	0.513	0.613	0.713	0.020	0.024	0.028	
D2	0.135	0.235	0.335	0.005	0.009	0.013							
E	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085	
E1	1.40	1.50	1.60	0.055	0.059	0.063	0.85	0.95	1.05	0.033	0.037	0.041	
E2	0.345	0.395	0.445	0.014	0.016	0.018							
E3	0.425	0.475	0.525	0.017	0.019	0.021							
е		0.65 BSC			0.026 BSC	;	0.65 BSC			0.026 BSC			
K		0.275 TYP			0.011 TYP	1	0.275 TYP 0.011 TYP						
K1	0.400 TYP 0.016 TYP			1	0.320 TYP			0.013 TYP					
K2	0.240 TYP 0.009 T			0.009 TYP	1	0.252 TYP			0.010 TYP				
К3	0.225 TYP 0.009 TYP												
K4	0.355 TYP 0.014 TY			0.014 TYP	1								
L	0.175	0.275	0.375	0.007	0.011	0.015	0.175	0.275	0.375	0.007	0.011	0.015	
Т							0.05	0.10	0.15	0.002	0.004	0.006	
ECN: C-07431 - Rev. C. 06-Aug-07													

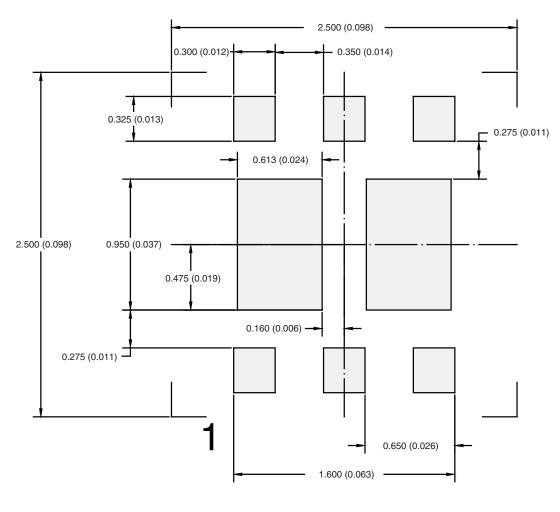
DWG: 5934

Document Number: 73001 06-Aug-07

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RECOMMENDED PAD LAYOUT FOR PowerPAK® SC70-6L Dual



Dimensions in mm (inches)

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APPLICATION NOT

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